FORM PTO-1449 (MODIFIED) ATTORNEY DOCKET NO. SERIAL NO. LIST OF PATENTS AND Berkey 47-9-6B To Be Assigned **PUBLICATIONS** FOR APPLICANTS INFORMATION DISCLOSURE STATEMENT APPLICANT Berkey et al.

FILING DATE: Herewith

GROUP: To Be Assigned

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A A	AA	1,283,333	10/29/18	Shaw		Ciass	
	AB	2,188,121	1/23/40	Smith	47	78.1	
	AC	3,740,207	6/19/73	Bogrets et al.	65	67	
	AD	3,933,454	1/20/76	DeLuca	65	3	
	AE	4,221,825	9/9/80	Guerder et al.	427	34	
	AF	4,345,928	8/24/82	Kawachi et al.	65	18.2	
	AG	4,363,647	12/14/82	Bachman et al.	65	18.2	
	AH	4,612,023	9/16/86	Kreutzer et al.	65	32	
	ΑI	4,650,511	3/17/87	Koya et al.	65	30.1	<u> </u>
	AJ	4,666,495	5/19/87	Kreutzer et al.	65	258	-
	AK	4,789,389	12/6/88	Schermerhorn et al.	65	31.2	
	AL	4,917,718	4/17/90	Berkey	65	108	
	AM	5,043,002	8/27/91	Dobbins et al.	65	31.2	
	AN	5,326,729	7/5/94	Yaba et al.	501	54	
	AO	5,364,433	11/15/94	Nishimura et al.	65	17.4	
	AP	5,410,428	4/25/95	Yamagata et al.	359	350	
	AQ	5,415,953	5/16/95	Alpay et al.	430	5	
	AR	5,474,589	12/12/95	Ohga et al.	65	397	
	AS	5,599,371	2/4/97	Cain et al.	65	413	
	AT	5,609,666	3/11/97	Heitmann	65	421	
	AU	5,655,046	8/5/97	Todoroki et al.	385	144	
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ı	AW	5,667,547	9/16/97	Christiansen et al.	65	17.4	
	AX	5,668,067	9/16/97	Araujo et al.	501	54	
	AY	5,679,125	10/21/97	Hiraiwa et al.	65	397	
-PY	_ AZ	5,683,483	11/4/97	Yosiaki et al.	65	102	1,

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FORM PTO-1449 (MODIFIED)

LIST OF PATENTS AND PUBLICATIONS FOR APPLICANTS INFORMATION DISCLOSURE STATEMENT

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SERIAL NO.

Berkey 47-9-6B

To Be Assigned

APPLICANT Berkey et al.

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	AB1	5,702,495	12/30/97	Hiraiwa et al.	65	17.1	
-	AC1	5,702,847	12/30/97	Tarumoto et al.	430	5	
	AD1	5,707,908	1/13/98	Komine et al.	501	53	
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	AF1	5,764,345	6/9/98	Fladd et al.	356	35.5	
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	AC	0 401 845 A2	12/12/90	EPO	G02B	1/00	Х	
	AD	0 483 752 A2	5/6/92	EPO	C03C	3/06	X	
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	AF	0 607 433 B1	11/4/98	EPO	C03B	23/06	X	
	AG	0 636 586 A1	2/1/95	EPO	C03C	3/06	X	
	AH	0 870 737 A1	10/14/98	EPO	C03C	3/06	X	
	AI	0 901 989 A1	3/17/99	EPO	C03B	19/14	Х	
	AJ	2,184,434	6/24/87	United Kingdom	C03B	20/00	X	
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	AM	1-138145	5/31/89	Japan			X	
9	AN	62-235223	10/15/87	Japan (abstract)	C03B	20/00		X
#60	AO	67/22389	11/1/67	Japan				X

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_}	<i>4 </i>	excimer-laser-induced densification of fused silica, OPTICS LETTERS/Vol.
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	AB	Roger J. Araujo, Nicholas F. Borrelli and Charlene Smith, INDUCED
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	AC	George H. Beall, INDUSTRIAL APPLICATIONS OF SILICA, Reviews in
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	AL	James A. McClay and Angela S.L. McIntyre, 157 nm optical lithography:
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	AM	Taro Moritani et al., "Glass Engineering Handbook," April 20, 1964, Asakura
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	AW	PTO: 96-0383, Journal, Title: Sheet Glass
	AX	Corning HPFS®, ArF Grade, Product Literature, 1999
	AY	Shin-Etsu Chemical Homepage, Semiconductor Materials Division,
		http://www.shinetsu.co.jp/english/profile/division/sem-div/sem-div.html,
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>	7	Chemical Reactivity,
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LIST OF PATENTS AND PUBLICATIONS FOR APPLICANTS INFORMATION

Berkey 47-9-6B

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APPLICANT Berkey et al.

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]]	AB1	Product Information, Isimoto Co., Ltd. Homepage,
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	AC1	High Purity Quartz Glass Products, http://www.toshiba-
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	AD1	Heraeus Quarzglas, Fused Silica for 157 nm photomasks, Bruno Uebbing 157
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	AG1	Heraeus Amersil, Product Literature, The Leader in Silica Glass & Fabricated
,		Quartz Glass: Diffusion Tubes, (9/14/99)
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		Quartz Glass Semiconductor Products: Furnace Tubes, (9/14/99)
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	AN	1	Encyclopedia Britannica Online Article, blow molding, (8/30/99)
	AO		Encyclopedia Britannica Online Article, glassblowing (8/30/99)
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	AR		Graphite Die Mold, Product Literature,
			http://graphitediemold.com/product.html (8/23/99)
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REFERENCE DESIGNATION

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Examiner Initial		Document Number	Date	Name	Class	Sub- Class	Filing Date if Approp.
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	AB	5,935,733	8/10/99	Scott et al.	430	5	
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	AD	5,699,183	12/16/97	Hiraiwa et al.	359	355	
TH(AE	6,087,283	7/11/00	Jinbo et al.	501	54	
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	AG						† · · · · · · · · · · · · · · · · · · ·

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	AI	0 691 312	1/10/96	EPO	C03C	3/06	X	
	AJ	0 147 029	10/30/84	EPO	C03B	37/016	X	
	AK	0 691 312	1/10/96	EPO	C03C	3/06	Х	
	AL	0 735 006	10/2/96	EPO	C03B	19/14	Х	
	AM	257,590	3/24/27	United Kingdom				
	AN	00/24684	5/4/00	PCT	C03B	32/00	X	
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	AP	2,184,434	6/24/87	United Kingdom	C03B	20/00	<u> </u>	1
	AQ	P2001-19450A	1/23/01	Japan	C03B	20/00	Tx	1
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